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U.S. UTILITY Patent Application

O.I.P.E. SCANNED.

PATENT DATE

С	LASS	SUBCLASS		ART UNIT		EXAMINER	•	_
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	APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER		
	09/967044	D	438	(-9	2812			

Douglas Grider

Method for transistor gate dielectric layer with uniform nitrogen concentration

585

PTO-2040 12/99 **ISSUING CLASSIFICATION ORIGINAL CROSS REFERENCE(S)** CLASS **SUBCLASS CLASS** SUBCLASS (ONE SUBCLASS PER BLOCK) INTERNATIONAL CLASSIFICATION Continued on Issue Slip Inside File Jacket

TERMINAL	DRAWINGS			CLAIMS ALLOWED		
DISCLAIMER	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.	
☐ The term of this patent				NOTICE OF ALLOWANCE MAILED		
subsequent to (date) has been disclaimed.	(Assistant Examiner)		(Date)			
The term of this patent shall			·			
not extend beyond the expiration date of U.S Patent. No.				ISS	UE FEE	
				Amount Due	Date Paid	
	(Primary Examiner)		(Date)			
The terminalmonths of this patent have been disclaimed.				ISSUE BAT	TCH NUMBER	
	(Legal Instrume	ents Examiner)	(Date)			
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